
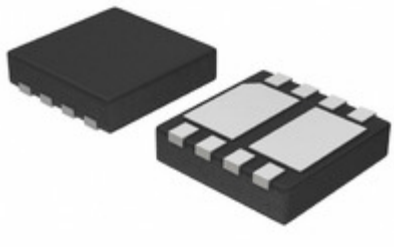
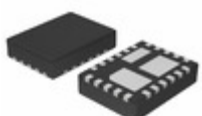
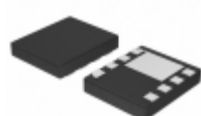

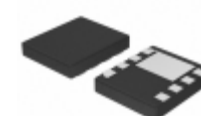
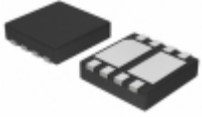
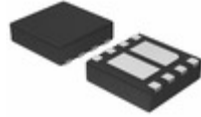
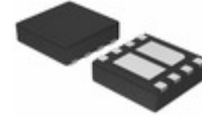
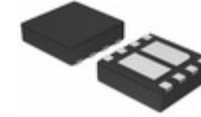
	<h2 style="color: red;">NUS5531MTR2G</h2>
	<p>Hersteller-Teilenummer: NUS5531MTR2G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET/BJT SGL P-CH 12V 8-WDFN</p> <hr/> <p>Datenblätter:  NUS5531MTR2G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 58819 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NUS5531MTR2G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET/BJT SGL P-CH 12V 8-WDFN
Kategorie	Diskrete Halbleiterprodukte > Transistoren -
Teilstatus	58819 pcs Stock
Serie	-
Spannung - Nennwert	20V PNP, 12V P-Channel
Befestigungsart	Surface Mount
Aktuelle Bewertung	2A PNP, 5.47A P-Channel
Anwendungen	General Purpose
Verpackung / Gehäuse	8-WDFN Exposed Pad
Supplier Device-Gehäuse	8-DFN (3x3)
Transistor-Typ	PNP, P-Channel
Verpackung	Tape & Reel (TR)















NUS5531MTR2G ist neu im Original, Suche NUS5531MTR2G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NUS5531MTR2G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NUS5531MTR2G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NUS6160MNTWG AMI Semiconductor / ON Semiconductor IC OVP LOW PRO W/MOSFET 22-QFN</p>	 <p>NUS3065MUTAG AMI Semiconductor / ON Semiconductor IC OVP LOW PRO W/MOSFET 8-TLLGA</p>	 <p>NUS6189MNTWG AMI Semiconductor / ON Semiconductor IC OVP LOW PRO W/MOSFET 22-QFN</p>	 <p>NUS3055MUTAG AMI Semiconductor / ON Semiconductor IC OVP LOW PRO W/MOSFET 8-TLLGA</p>
 <p>NUS3116MTR2G AMI Semiconductor / ON Semiconductor IC MOSFET MAIN SW DUAL BJT 8-DFN</p>	 <p>NUS3046MNT1G AMI Semiconductor / ON Semiconductor IC OVP W/MOSFET 8-DFN</p>	 <p>NUS3045MNT1 AMI Semiconductor / ON Semiconductor IC OVP W/30V P-CH MOSFET DFN8</p>	 <p>NUS5530MNR2G AMI Semiconductor / ON Semiconductor IC MOSFET W/PNP SW TRANS 8-DFN</p>

heiße Teile

Mehr

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 HKQ0603U2N3B-T	 IRKT170-04D20	 IRKT180-14	 KK25HB120	 LA1830ST-AUD
 LD29080DT3.3R	 LMH6725MAX	 LTC1470CS8#TRPBF	 LTC3417EDHC#TRPBF	 LXES03AAA1-134
 MAZ31100ML	 MURS120TR	 N0882NS450	 NT6813KG-30030/M2A	 NUS2045MNT1G
 NUS2401SNT1	 NUS2401SNT1G	 NUS3045MNT1	 NUS3045MNT1G	 NUS3046MNT1G
 NUS3055MUTAG	 NUS3065MUTAG	 NUS3116MTR2G	 NUS5530MNR2G	 OP162GSZ-REEL
 OPA695IDR	 PDI1394P25BY	 REG103UA-AG4	 RT9054-GPGQW	 RT9293BGJ6
 SI7196DP-T1-GE3	 SKT630/12E	 SLB9670VQ2.0FW7.40	 SM5164RV-G-E2	 SMBJ7.5A-E3/52
 TDA9815/V3	 TLE4275G	 TLV2622IDGKR	 VI-26B-CY	 VS-31DQ09

Contact us: Info@Y-IC.com

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